

# Switch-mode Power Rectifier 150 V, 20 A

# MBRF20H150CTG, MBR20H150CTG

#### **Features and Benefits**

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capability
- 20 A Total (10 A Per Diode Leg)
- Guard-Ring for Stress Protection
- These Devices are Pb-Free and are RoHS Compliant

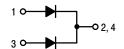
#### **Applications**

- Power Supply Output Rectification
- Power Management
- Instrumentation

#### **Mechanical Characteristics:**

- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight (Approximately): 1.9 Grams (TO-220 & TO-220FP)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

# SCHOTTKY BARRIER RECTIFIER 20 AMPERES, 150 VOLTS





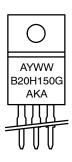


TO-220 FULLPAK™ CASE 221D

TO-220 CASE 221A STYLE 6

#### MARKING DIAGRAMS





TO-220FP

A = Assembly Location

Y = Year
WW = Work Week
B20H150 = Device Code
G = Pb-Free Device
AKA = Polarity Designator

### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 2.

#### MAXIMUM RATINGS (Per Diode Leg)

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	150	V
	Per Leg) Device)	I <sub>F(AV)</sub>	10 20	Α
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	180	Α	
Operating Junction Temperature (Note 1)	$T_J$	-20 to +150	°C	
Storage Temperature		T <sub>stg</sub>	-65 to +150	°C
Voltage Rate of Change (Rated V <sub>R</sub> )	dv/dt	10,000	V/μs	
ESD Ratings: Machine M Human Body Mc			> 400 > 8000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

	Symbol	Value	Unit
inction-to-Ambient	$R_{ heta$ JC $R_{ heta}$ JA	2.0 45	°C/W
Ц	- Junction-to-Case unction-to-Ambient - Junction-to-Case	- Junction-to-Case $R_{ heta$ JC unction-to-Ambient $R_{ heta}$ JA	- Junction-to-Case $R_{\theta JC}$ 2.0 unction-to-Ambient $R_{\theta JA}$ 45

### **ELECTRICAL CHARACTERISTICS** (Per Diode Leg)

Rating	Symbol	Тур	Max	Unit
$\label{eq:maximum Instantaneous Forward Voltage (Note 2)} \begin{array}{c} (I_F=5~A,~T_C=25^\circ C)\\ (I_F=5~A,~T_C=125^\circ C)\\ (I_F=5~A,~T_C=25^\circ C)\\ (I_F=10~A,~T_C=25^\circ C)\\ (I_F=10~A,~T_C=125^\circ C) \end{array}$	VF	0.72 0.57 0.87 0.65	0.60 0.68	V
Maximum Instantaneous Reverse Current (Note 2) (Rated DC Voltage, $T_C$ = 25°C) (Rated DC Voltage, $T_C$ = 125°C)	İR		50 30	μA mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **ORDERING INFORMATION**

Device Order Number	Package Type	Shipping
MBR20H150CTG	TO-220 (Pb-Free)	50 Units / Rail

#### **DISCONTINUED** (Note 3)

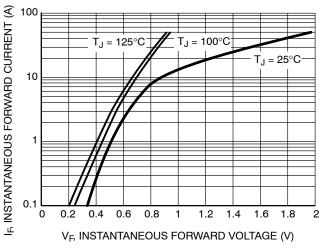
MBRF20H150CTG	TO-220FP	50 Units / Rail
	(Pb-Free)	

<sup>3.</sup> **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on <a href="https://www.onsemi.com">www.onsemi.com</a>.

<sup>1.</sup> The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

<sup>2.</sup> Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

100



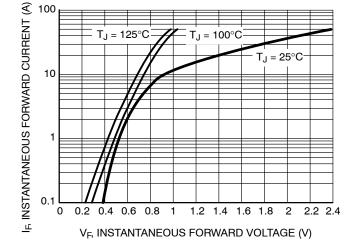
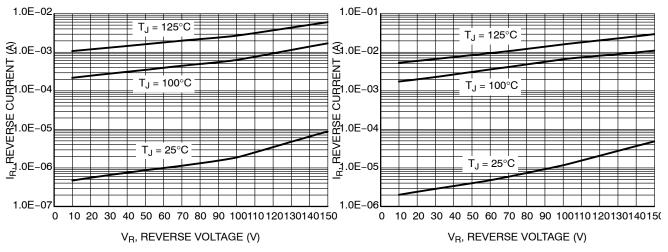


Figure 1. Typical Forward Voltage

Figure 2. Maximum Forward Voltage



**Figure 3. Typical Reverse Current** 

Figure 4. Maximum Reverse Current

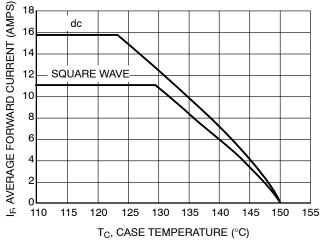


Figure 5. Current Derating

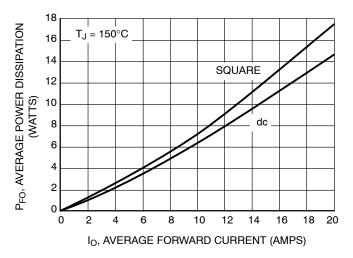


Figure 6. Forward Power Dissipation

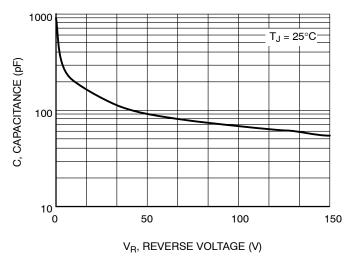


Figure 7. Capacitance

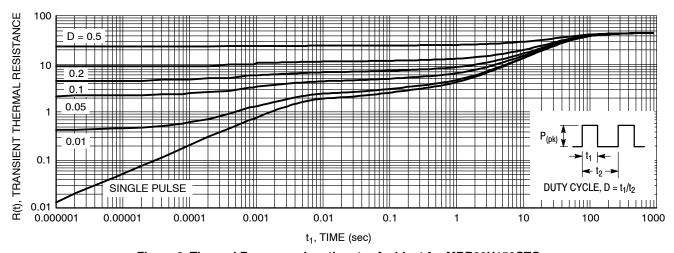


Figure 8. Thermal Response Junction-to-Ambient for MBR20H150CTG

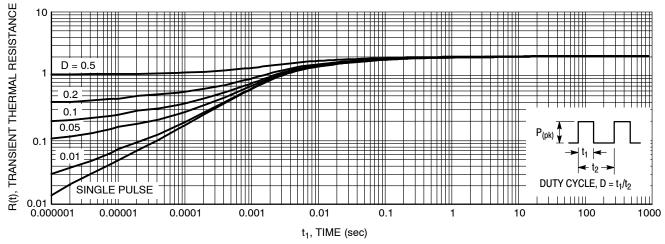


Figure 9. Thermal Response Junction-to-Case for MBR20H150CTG

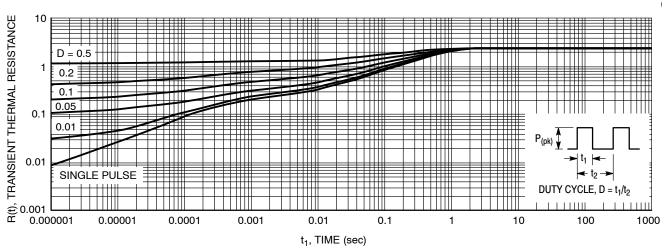


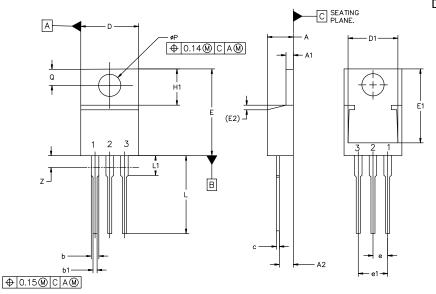
Figure 10. Thermal Response Junction-to-Case for MBRF20H150CTG





#### TO-220-3 10.10x15.12x4.45, 2.54P CASE 221A **ISSUE AL**

**DATE 05 FEB 2025** 



NOM 4.45 1.28 2.42	MAX 4.83 1.41 2.79		
1.28	1.41		
2.42			
	2.79		
4 7 4			
1.54	1.52		
0.80	0.96		
0.49	0.61		
10.10	10.53		
8.63	8.83		
15.12	15.75		
12.78	12.98		
1.27 REF			
	0.49 10.10 8.63 15.12 12.78		

MILLIMETERS				
DIM	MIN	NOM	MAX	
е	2.42	2.54	2.66	
e1	4.83	5.08	5.33	
H1	5.97	6.22	6.47	
L	12.70	13.49	14.27	
L1	2.80	3.45	4.10	
Q	2.54	2.79	3.04	
ØΡ	3.60	3.85	4.09	
Z			3.48	

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:	
PIN 1.	BASE	PIN 1.	BASE	PIN 1.	CATHODE	PIN 1.	MAIN TERMINAL 1
2.	COLLECTOR	2.	EMITTER	2.	ANODE	2.	MAIN TERMINAL 2
3.	EMITTER	3.	COLLECTOR	3.	GATE	3.	GATE
4.	COLLECTOR	4.	EMITTER	4.	ANODE	4.	MAIN TERMINAL 2
STYLE 5:		STYLE 6:		STYLE 7:		STYLE 8:	
PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	CATHODE	PIN 1.	CATHODE
2.	DRAIN	2.	CATHODE	2.	ANODE	2.	ANODE
3.	SOURCE	3.	ANODE	3.	CATHODE	3.	EXTERNAL TRIP/DELAY
4.	DRAIN	4.	CATHODE	4.	ANODE	4.	ANODE
STYLE 9:		STYLE 10:		STYLE 11:	:	STYLE 12:	:
PIN 1.	GATE	PIN 1.	GATE	PIN 1.	DRAIN	PIN 1.	MAIN TERMINAL 1
2.	COLLECTOR	2.	SOURCE	2.	SOURCE	2.	MAIN TERMINAL 2
3.	EMITTER	3.	DRAIN	3.	GATE	3.	GATE
4.	COLLECTOR	4.	SOURCE	4.	SOURCE	4.	NOT CONNECTED

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DESCRIPTION:	TO-220-3 10.10x15.12x4.4	TO-220-3 10.10x15.12x4.45, 2.54P	

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SCALE 1:1

#### TO-220 FULLPAK CASE 221D-03 ISSUE K

**DATE 27 FEB 2009** 

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**AYWW** 

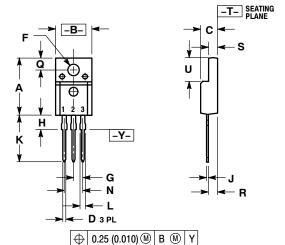
xxxxxxG

AKA

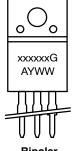
- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH
- 221D-01 THRU 221D-02 OBSOLETE, NEW STANDARD 221D-03.

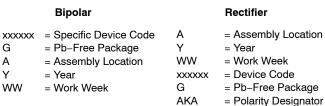
	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.617	0.635	15.67	16.12
В	0.392	0.419	9.96	10.63
С	0.177	0.193	4.50	4.90
D	0.024	0.039	0.60	1.00
F	0.116	0.129	2.95	3.28
G	0.100 BSC		2.54 BSC	
Н	0.118	0.135	3.00	3.43
J	0.018	0.025	0.45	0.63
K	0.503	0.541	12.78	13.73
L	0.048	0.058	1.23	1.47
N	0.200	BSC	5.08	BSC
Q	0.122	0.138	3.10	3.50
R	0.099	0.117	2.51	2.96
S	0.092	0.113	2.34	2.87
U	0.239	0.271	6.06	6.88

### **MARKING DIAGRAMS**



STYLE 1: PIN 1. GATE STYLE 2: PIN 1. BASE STYLE 3: PIN 1. ANODE 2. COLLECTOR 3. EMITTER CATHODE
 ANODE 2. DRAIN 2. 3. SOURCE STYLE 6: PIN 1. MT 1 2. MT 2 3. GATE STYLE 4: PIN 1. CATHODE STYLE 5: PIN 1. CATHODE 2. ANODE 3. GATE ANODE 3. CATHODE





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